

Aaron D. Franklin

Curriculum Vita

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Education

Ph.D. Electrical Engineering	Purdue University West Lafayette, IN	2008
B.S. Electrical Engineering Minor: Communication	Arizona State University Tempe, AZ	2004

Honors and Awards

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- IBM Labyrinth Award for Invention Accomplishments 2014
 - IBM Outstanding Technical Achievement Award 2014
 - IBM Research Outstanding Contributor Award 2013
 - GOMAC Technology Conference #1 Outstanding Paper Award 2012
 - IBM Invention Achievement Awards 2009, 2011, 2012, 2013
 - GOMAC Technology Conference Meritorious Paper Award 2010
 - National Science Foundation (NSF) Graduate Research Fellowship (GRF) 2005 - 2008
 - First place poster prize and NSF travel scholarship for Nano and Giga Conference 2007
 - Materials Research Society (MRS) Graduate Student Silver Award 2006
 - NASA Institute for Nanoelectronics and Computing (INaC) Fellowship 2005 - 2006
 - Purdue University Andrews Recruiting Fellowship 2005 - 2006
 - Graduate of Barrett Honors College at Arizona State University 2004
 - Arizona State University Distinguished Electrical Engineering Senior of the Year Award 2004
 - Fifteen top-ranking awards in persuasive, informative, and impromptu speaking and debate at various Intercollegiate Speech and Debate tournaments 2001 - 2002

Academic and Professional Appointments

Executive Director of Graduate Studies <i>Duke University, Department of Electrical and Computer Engineering (ECE)</i>	2017 - Present
Associate Professor <i>Duke University, Department of Electrical and Computer Engineering (ECE) & Department of Chemistry</i>	2014 - Present
Adjunct Assistant Professor <i>Columbia University, Department of Electrical Engineering</i>	2013 - 2014
Research Staff Member <i>IBM, T. J. Watson Research Center, Physical Science and Silicon Departments</i>	2008 - 2014
NSF Graduate Research Fellow <i>Purdue University, School of Electrical and Computer Engineering</i>	2004 - 2008

Publications (h-index = 28)

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1. F. A. McGuire, Y. -C. Lin, K. Price, G. B. Rayner, S. Khandelwal, S. Salahuddin, and **A. D. Franklin**, "Sustained sub-60 mV/decade switching via the negative capacitance effect in MoS₂ transistors," *Nano Lett.*, vol. 17, pp. 4801-4806, 2017.
 2. K. M. Price, K. E. Schauble, F. A. McGuire, D. B. Farmer, and **A. D. Franklin**, "Uniform growth of sub-5 nm high-κ dielectrics on MoS₂ using plasma-enhanced atomic layer deposition," *ACS Appl. Mater. Interfaces*, vol. 9, pp. 23072-23080, 2017.
 3. J. B. Andrews, C. Cao, M. Brooke, and **A. D. Franklin**, "Noninvasive material thickness detection by aerosol jet printed sensors enhanced through metallic carbon nanotube ink," *IEEE Sensors Journal*, vol. 17, pp. 4612-4618, 2017.
 4. Y. -C. Lin, F. A. McGuire, and **A. D. Franklin**, "On the effects of capping layers and thermal annealing for ferroelectric Hf_{0.5}Zr_{0.5}O₂," (*in review*).
 5. C. Cao, J. B. Andrews, and **A. D. Franklin**, "Completely printed, flexible, stable, and hysteresis-free carbon nanotube thin-film transistors," *Adv. Electronic Mater.*, vol. 3, pp. 1700057, 2017.

6. M. J. Catenacci, P. F. Flowers, C. Cao, J. B. Andrews, **A. D. Franklin**, and B. J. Wiley, "Fully printed memristors from Cu-SiO₂ core-shell nanowire composites," *J. Electronic Mater.*, 2017.
7. N. D. Cox, C. D. Cress, J. E. Rossi, I. Puchades, A. Merrill, **A. D. Franklin**, and B. J. Landi, "Modification of silver/single-wall carbon nanotube electrical contact interfaces via ion irradiation," *ACS Appl. Mater. Interfaces*, vol. 9, pp. 7406-7411, 2017.
8. D. Joh, F. McGuire, R. Abedini-Nassab, J. Andrews, R. Achar, Z. Zimmers, D. Mozhdghi, R. Blair, F. Albarghouthi, W. Oles, J. Richter, C. Fontes, A. Hucknall, B. Yellen, **A. D. Franklin**, and A. Chilkoti, "Poly(oligo(ethylene glycol) methyl ether methacrylate) brushes on high- κ metal oxide dielectric surfaces for bioelectrical environments," *ACS Appl. Mater. Interfaces*, vol. 9, pp. 5522-5529, 2017.
9. S. Najmaei, S. Lei, R. Burke, B. M. Nichols, A. George, P. M. Ajayan, **A. D. Franklin**, J. Lou, and M. Dubey, "Enabling ultra-sensitive photo-detection through control of interface properties in molybdenum disulfide atomic layers," *Sci. Rep.*, vol. 6, pp. 39465, 2016.
10. F. A. McGuire, Z. Cheng, K. Price, and **A. D. Franklin**, "Sub-60 mV/decade switching in 2D negative capacitance field-effect transistors with integrated ferroelectric polymer," *Appl. Phys. Lett.*, vol. 109, pp. 093101, 2016.
11. Z. Cheng, J. A. Cardenas, F. A. McGuire, S. Najmaei, and **A. D. Franklin**, "Modifying the Ni-MoS₂ contact interface using a broad-beam ion source," *IEEE Electron Device Lett.*, vol. 37, pp. 1234-1237, 2016.
12. C. Cao, J. B. Andrews, A. Kumar, and **A. D. Franklin**, "Improving contact interfaces in fully printed carbon nanotube thin-film transistors," *ACS Nano*, vol. 10, pp. 5221-5229, 2016.
13. **A. D. Franklin**, "Nanomaterials in transistors—from high-performance to thin-film applications," *Science*, vol. 349, pp. aab2750, 2015.
14. J. Li, **A. D. Franklin**, and J. Liu, "Gate-free electrical breakdown of metallic pathways in single-walled carbon nanotube crossbar networks," *Nano Lett.*, vol. 15, pp. 6058-6065, 2015.
15. Q. Cao, S. -J. Han, J. Tersoff, **A. D. Franklin**, Y. Zhu, Z. Zhang, G. S. Tulevski, J. Tang, and W. Haensch, "End-bonded contacts for carbon nanotube transistors with low, size-independent resistance," *Science*, vol. 350, pp. 68-72, 2015.
16. C. -S. Lee, E. Pop, **A. D. Franklin**, W. Haensch, and H. -S. P. Wong, "A compact virtual-source model for carbon nanotube field-effect transistors in the sub-10-nm regime—Part II: Extrinsic elements, performance assessment, and design optimization," *IEEE Trans. Electron Devices*, vol. 62, pp. 3070-3078, 2015.
17. C. -S. Lee, E. Pop, **A. D. Franklin**, W. Haensch, and H. -S. P. Wong, "A compact virtual-source model for carbon nanotube field-effect transistors in the sub-10-nm regime—Part I: Intrinsic elements," *IEEE Trans. Electron Devices*, vol. 62, pp. 3061-3069, 2015.
18. G. S. Tulevski, **A. D. Franklin**, D. Frank, J. M. Lobe, Q. Cao, H. Park, A. Afzali, S. -J. Han, J. B. Hannon, and W. Haensch, "Toward high-performance digital logic technology with carbon nanotubes," *ACS Nano*, vol. 8, pp. 8730-8745, 2014.
19. **A. D. Franklin**, D. B. Farmer, and W. Haensch, "Defining and overcoming the contact resistance challenge in scaled carbon nanotube transistors," *ACS Nano*, vol. 8, pp. 7333-7339, 2014.
20. B. Kim, **A. D. Franklin**, C. Nuckolls, W. Haensch, and G. S. Tulevski, "Achieving low-voltage thin-film transistors using carbon nanotubes," *Appl. Phys. Lett.*, vol. 105, pp. 063111, 2014.
21. D. Shahrjerdi, **A. D. Franklin**, S. Oida, J. A. Ott, G. S. Tulevski, and W. Haensch, "High-performance air-stable n-type carbon nanotube transistors with erbium contacts," *ACS Nano*, vol. 7, pp. 8303-8308, 2013.
22. **A. D. Franklin**, "The road to carbon nanotube transistors," *Nature*, vol. 498, pp. 443-444, 2013.
23. **A. D. Franklin**, S. O. Koswatta, D. B. Farmer, J. T. Smith, L. Gignac, C. M. Breslin, S. -J. Han, G. S. Tulevski, H. Miyazoe, W. Haensch, and J. Tersoff, "Carbon nanotube complementary wrap-gate transistors," *Nano Lett.*, vol. 13, pp. 2490-2495, 2013.
24. J. Luo, L. Wei, C. -S. Lee, **A. D. Franklin**, X. Guan, E. Pop, D. A. Antoniadis, and H. -S. P. Wong, "A compact model for carbon nanotube field-effect transistors including non-idealities and calibrated with experimental data down to 9 nm gate length," *IEEE Trans. Electron Devices*, vol. 60, pp. 1834-1843, 2013.
25. J. T. Smith, **A. D. Franklin**, D. B. Farmer, and C. Dimitrakopoulos, "Reducing contact resistance in graphene devices through contact area patterning," *ACS Nano*, vol. 7, pp. 3661-3667, 2013.

26. G. S. Tulevski, **A. D. Franklin**, and A. Afzali-Ardakani, "High purity isolation and quantification of semiconducting carbon nanotubes via column chromatography," *ACS Nano*, vol. 7, pp. 2971-2976, 2013.
27. **A. D. Franklin**, S. Oida, D. B. Farmer, J. T. Smith, S. -J. Han, C. M. Breslin, and L. Gignac, "Stacking graphene channels in parallel for enhanced performance with the same footprint," *IEEE Electron Device Lett.*, vol. 34, pp. 556-558, 2013.
28. **A. D. Franklin**, N. A. Bojarczuk, and M. Copel, "Consistently low subthreshold swing in carbon nanotube transistors using lanthanum oxide," *Appl. Phys. Lett.*, vol. 102, pp. 013108, 2013.
29. **A. D. Franklin**, S. Koswatta, D. B. Farmer, G. S. Tulevski, J. T. Smith, H. Miyazoe, and W. Haensch, "Scalable and fully self-aligned n-type carbon nanotube transistors with gate-all-around," *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 4.5.1-4.5.4, 2012.
30. H. Park, A. Afzali, S. -J. Han, G. S. Tulevski, **A. D. Franklin**, J. Tersoff, J. B. Hannon, and W. Haensch, "High-density integration of carbon nanotubes via chemical self-assembly," *Nature Nanotechnol.*, vol. 7, pp. 787-791, 2012.
31. Q. Cao, S. -J. Han, G. S. Tulevski, **A. D. Franklin**, and W. Haensch, "Evaluation of field-effect mobility and contact resistance of transistors that use solution-processed single-walled carbon nanotubes," *ACS Nano*, vol. 6, pp. 6471-6477, 2012.
32. S. -J. Han, D. Reddy, G. D. Carpenter, **A. D. Franklin**, and K. A. Jenkins, "Current saturation in sub- μm graphene transistors with thin gate dielectric: Experiment, simulation, and theory," *ACS Nano*, vol. 6, pp. 5220-5226, 2012.
33. **A. D. Franklin**, M. Luisier, S. -J. Han, G. Tulevski, C. M. Breslin, L. Gignac, M. S. Lundstrom, and W. Haensch, "Sub-10 nm carbon nanotube transistor," *Nano Lett.*, vol. 12, pp. 758-762, 2012.
34. **A. D. Franklin**, G. S. Tulevski, S. -J. Han, D. Shahrjerdi, Q. Cao, H. -Y. Chen, H. -S. P. Wong, and W. Haensch, "Variability in carbon nanotube transistors: Improving device-to-device consistency," *ACS Nano*, vol. 6, pp. 1109-1115, 2012.
35. **A. D. Franklin**, S. -J. Han, A. A. Bol, and V. Perebeinos, "Double contacts for improved performance of graphene transistors," *IEEE Electron Device Lett.*, vol. 33, pp. 17-19, 2012.
36. **A. D. Franklin**, S. -J. Han, G. S. Tulevski, M. Luisier, C. M. Breslin, L. Gignac, M. S. Lundstrom, and W. Haensch, "Sub-10 nm carbon nanotube transistor," *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 23.7.1-23.7.3, 2011.
37. S. -J. Han, A. Valdes-Garcia, A. Bol, **A. D. Franklin**, D. Farmer, K. A. Jenkins, and W. Haensch, "Graphene technology with reversed-T gate and RF passives on 200mm platform," *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 2.2.1-2.2.4, 2011.
38. D. Shahrjerdi, **A. D. Franklin**, S. Oida, G. S. Tulevski, S. -J. Han, J. B. Hannon, and W. Haensch, "High device yield carbon nanotube NFETs for high-performance logic applications," *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 23.3.1-23.3.4, 2011.
39. S. -J. Han, K. A. Jenkins, A. V. Garcia, **A. D. Franklin**, A. A. Bol, and W. Haensch, "High-frequency graphene voltage amplifier," *Nano Lett.*, vol. 11, pp. 3690-3693, 2011.
40. **A. D. Franklin**, "Replacing silicon with carbon nanotubes—Why it's still worth considering," *EE Web Pulse Magazine*, issue 13, pp. 8-10, 2011.
41. **A. D. Franklin**, S. -J. Han, A. A. Bol, and W. Haensch, "Effects of nanoscale contacts to graphene," *IEEE Electron Device Lett.*, vol. 32, pp. 1035-1037, 2011.
42. S.-J. Han, J. Chang, **A. D. Franklin**, A. A. Bol, R. Loesing, D. Guo, G. S. Tulevski, W. Haensch, and Z. Chen, "Wafer scale fabrication of carbon nanotube FETs with embedded poly-gates," *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 9.1.1-9.1.4, 2010.
43. **A. D. Franklin** and Z. Chen, "Length scaling of carbon nanotube transistors," *Nature Nanotechnol.*, vol. 5, pp. 858-862, 2010.
44. **A. D. Franklin**, A. Lin, H. -S. P. Wong, and Z. Chen, "Current scaling in aligned carbon nanotube array transistors with local bottom gating," *IEEE Electron Device Lett.*, vol. 31, pp. 644-646, 2010.
45. R. A. Sayer, S. Kim, **A. D. Franklin**, S. Mohammadi, and T. S. Fisher, "Shot noise thermometry for thermal characterization of templated carbon nanotubes," *IEEE Trans. Components and Packaging Technol.*, vol. 33, pp. 178-183, 2010.

46. T. L. Westover, **A. D. Franklin**, B. A. Cola, T. S. Fisher, and R. G. Reifenberger, "Photo- and thermionic emission from potassium-intercalated carbon nanotube arrays," *J. Vac. Sci. Technol. B*, vol. 28, pp. 423-434, 2010.
47. **A. D. Franklin**, G. Tulevski, J. B. Hannon, Z. Chen, "Can carbon nanotube transistors be scaled without performance degradation?" *IEEE International Electron Device Meeting (IEDM) Technical Digest*, pp. 1-4, 2009.
48. **A. D. Franklin**, R. A. Sayer, T. D. Sands, D. B. Janes, and T. S. Fisher, "Vertical carbon nanotube devices with nanoscale lengths controlled without lithography," *IEEE Trans. Nanotechnol.*, vol. 8, pp. 469-476, 2009. (COVER ARTICLE)
49. **A. D. Franklin**, R. A. Sayer, T. D. Sands, T. S. Fisher, and D. B. Janes, "Toward surround gates on vertical single-walled carbon nanotube devices," *J. Vac. Sci. Technol. B*, vol. 27, pp. 821-826, 2009.
50. J. C. Claussen, **A. D. Franklin**, A. Haque, M. Porterfield, and T. S. Fisher, "Electrochemical biosensor of nanocube-augmented carbon nanotube networks," *ACS Nano*, vol. 3, pp. 37-44, 2009. (COVER ARTICLE)
51. **A. D. Franklin**, J. C. Claussen, T. D. Sands, T. S. Fisher, and D. B. Janes, "Independently addressable fields of porous anodic alumina embedded in SiO₂ on Si," *Appl. Phys. Lett.*, vol. 92, pp. 013122, 2008.
52. R. Voggu, C. S. Rout, **A. D. Franklin**, T. S. Fisher, and C. N. R. Rao, "Extraordinary sensitivity of the electronic structure and properties of single-walled carbon nanotubes to molecular charge-transfer," *J. Phys. Chem. C*, vol. 112, pp. 13053-13056, 2008.
53. J. T. Smith, Q. Hang, **A. D. Franklin**, D. B. Janes, and T. D. Sands, "Highly ordered diamond and hybrid triangle-diamond patterns in porous anodic alumina thin films," *Appl. Phys. Lett.*, vol. 93, pp. 043108, 2008.
54. **A. D. Franklin**, J. T. Smith, T. S. Fisher, T. D. Sands, K.-S. Choi, and D. B. Janes, "Controlled decoration of single-walled carbon nanotubes with Pd nanocubes," *J. Phys. Chem. C*, vol. 111, pp. 13756-13762, 2007.
55. **A. D. Franklin**, M. R. Maschmann, M. DaSilva, D. B. Janes, T. S. Fisher, and T. D. Sands, "In-place fabrication of nanowire electrode arrays for vertical nanoelectronics on Si substrates," *J. Vac. Sci. Technol. B*, vol. 25, pp. 343-347, 2007. Also, in *Virtual J. Nanoscale Sci. Technol.* 15, Iss. 9, 2007.
56. M. R. Maschmann, **A. D. Franklin**, T. D. Sands, and T. S. Fisher, "Optimization of porous anodic Al-Fe-Al structures for carbon nanotube synthesis," *Carbon*, vol. 45, pp. 2290-2296, 2007.
57. **A. D. Franklin**, M. R. Maschmann, A. Scott, D. B. Janes, T. D. Sands, and T. S. Fisher, "Lithography-free *in situ* Pd contacts to templated single-walled carbon nanotubes," *Nano Lett.*, vol. 6, pp. 2712-2717, 2006.
58. M. R. Maschmann, **A. D. Franklin**, P. B. Amama, D. N. Zakharov, E. A. Stach, T. D. Sands, and T. S. Fisher, "Vertical single- and double-walled carbon nanotubes grown from modified porous anodic alumina templates," *Nanotechnology*, vol. 17, pp. 3925-3929, 2006.

Book Chapters

1. **A. D. Franklin**, "Carbon nanotube electronics," *Emerging Nanoelectronic Devices*, ed. A. Chen, John Wiley & Sons, Ltd, Jan. 2015.
2. **A. D. Franklin**, M. R. Maschmann, and T. S. Fisher, "Integration of vertical carbon nanotube devices," *Encyclopedia of Semiconductor Nanotechnology*, ed. A. Umar, American Scientific Publishers, (in press), 2012.

Invited Talks

1. XXVI International Materials Research Congress 2017, "Printing of biologicals and nanomaterials for point-of-care assays," Cancun, Mexico, Aug. 2017.
2. International Workshop on 2D Atomic Sheets, "Harnessing the Unique Usefulness of 2D Materials Through Scaling, Stacking, and Printing," College Park, MD, July 2017.
3. 2017 Symposium on VLSI Technology, "Scaling, stacking, and printing: How 1D and 2D nanomaterials still hold promise for a new era of electronics," Kyoto, Japan, June 2017.
4. Illumina, "Scaling, printing, and sensing: A new era for electronics made possible using nanomaterials," San Diego, CA, Jan. 2017.
5. Brigham Young University, "Scaling, printing, and sensing: A new era for electronics made possible using nanomaterials," Provo, UT, Oct. 2016.
6. IBM T. J. Watson Research Center, "Scaling, printing, and sensing: A new era for electronics made possible using nanomaterials," Yorktown Heights, NY, July 2016.

7. International Symposium on Devices and Applications of Two-Dimensional Materials, "Stacking, damaging, and etching: Optimizing performance in 2D electronic devices," Fudan University, Shanghai, China, July 2016.
8. Emerging Technologies CMOS 2016 Conference, "Promises and challenges of nanomaterial in transistors: From high-performance to thin-film applications," Montreal, Quebec, Canada, May 2016.
9. TechConnect World 2016 - Nanotech, Microtech, Biotech, Cleantech, "Promises, problems, and practicalities of nanomaterials in transistors," National Harbor, MD, May 2016.
10. Phi Theta Kappa Honors Society General Meeting, "How the world works: Global perspectives," Mesa Community College, Mesa, AZ, Mar. 2016.
11. BYU Management Society - Phoenix-East Chapter, "The hidden truth behind our explosive technological revolution," Arizona State University, Tempe, AZ, Mar. 2016.
12. University of Minnesota, "Promises, problems, and practicalities for nanomaterials in transistors," Minneapolis, MN, Mar. 2016.
13. University of Notre Dame, "Promises, problems, and practicalities for nanomaterials in transistors," South Bend, IN, Jan. 2016.
14. MRS-ASM-AVS Joint Symposium, "Nanomaterials in Electronics," NC State, Raleigh, NC, Nov. 2015.
15. 41st Micro and Nano Engineering (MNE) conference, "Promises, problems, and practicalities of nanomaterial electronics," The Hague, Netherlands, Sept. 2015. - *KEYNOTE SPEAKER* -
16. Eindhoven University of Technology, "What role will nanomaterials play in electronics?" Eindhoven, Netherlands, Sept. 2015.
17. Illumina, "The pillars of nanomaterial-enabled devices: Purity, placement, and performance," San Diego, CA, Aug. 2015.
18. North Carolina State University, "What role will nanomaterials play in electronics?" Raleigh, NC, June 2015.
19. Army Research Laboratory (ARL), "Nanomaterials in the Next Switch?" Adelphi, MD, Apr. 2015.
20. University of North Carolina at Chapel Hill, "What role will nanomaterials play in electronics?" Chapel Hill, NC, Apr. 2015.
21. Government Microcircuit Applications & Critical Technology Conference (GOMAC Tech), "Nanomaterials in the next-switch?" St. Louis, MO, Mar. 2015.
22. American Chemical Society (ACS) Meeting, "How will carbon nanotubes impact the next generation of electronics?" Denver, CO, Mar. 2015.
23. Gordon Research Conference—Nanostructure Fabrication, "Prospects for bottom-up 1D and 2D nanoelectronics in high-performance computing," Biddeford, ME, Jul. 2014.
24. TechConnect World 2014 - Nanotech, Microtech, Biotech, Cleantech, "Prospects and challenges for carbon nanotube transistors in high performance nanoelectronics beyond 2020," National Harbor, MD, June 2014.
25. Device Research Conference (DRC) - Rump Session, "What are 2D devices and materials good for?" Santa Barbara, CA, Jun. 2014.
26. 1st International Workshop on Data-Abundant System Technology, "Latest advancements toward a carbon nanotube transistor technology," Stanford University, Palo Alto, CA, Apr. 2014.
27. Columbia University, "Next generation transistors: Where do carbon nanotubes fit in?," New York, NY, Mar. 2014.
28. Duke University, "Next generation transistors: Where do carbon nanotubes fit in?," Durham, NC, Feb. 2014.
29. International Semiconductor Device Research Symposium (ISDRS), "Latest developments toward a carbon nanotube transistor technology," Bethesda, MD, Dec. 2013.
30. Lithography Workshop, "Patterning needs and obstacles for a sub-10 nm carbon nanotube transistor technology," La Quinta, CA, Nov. 2013.
31. International Conference on Solid State Devices and Materials (SSDM), "Wrapping carbon nanotubes in a gate-all-around geometry," Fukuoka, Japan, Sept. 2013.

32. National Institute of Advanced Industrial Science and Technology (AIST), "The road ahead for transistors: Where do carbon nanotubes fit in?," Tsukuba, Japan, Sept. 2013.
33. Symposium on Recent Advances in Carbon-Based Nanoelectronics, "Scaling carbon nanotube transistors for a sub-10 nm digital technology," Peking University, Beijing, China, Jul. 2013.
34. Purdue University, "The road ahead for carbon nanotube transistors," West Lafayette, IN, Jun. 2013.
35. Arizona State University, "The road ahead for transistors," Tempe, AZ, Jun. 2013.
36. Material Research Society (MRS) Spring Meeting, "Nanoscale contacts to carbon nanomaterials," San Francisco, CA, Apr. 2013.
37. Stanford University, "Carbon nanotube transistor technology—Are we there yet?!", Palo Alto, CA, Apr. 2013.
38. University of California-Berkeley, "Digital technology from carbon nanotube transistors," Berkeley, CA, Apr. 2013.
39. CNTs for Digital Electronics Workshop, "Scaling and variability," NIST, Gaithersburg, MD, Sept. 2012.
40. Gordon Research Conference - Nanostructure Fabrication, "Carbon Nanotubes for a New Generation of Transistors," University of New England, Biddeford, ME, Jul. 2012.
41. Georgia Institute of Technology, "Carbon Nanotubes—Why They're Still Worth Pursuing for Next-Generation Transistors", Atlanta, GA, Mar. 2012.
42. IBM Materials Research Community, "Promises and Challenges for Achieving a Digital Technology with Carbon Nanotube Transistors," Yorktown Heights, NY, Mar. 2012.
43. NYS Meeting of the American Physical Society, "Carbon nanotubes: Can they really replace silicon?" University of Albany, NY, Apr. 2011.
44. Lester Eastman Conference on High Performance Devices, "Interfacing with carbon nanomaterials—difficulties in accessing the intrinsic properties," Rensselaer Polytechnic Institute, NY, Aug. 2010.
45. University of Notre Dame, "Carbon nanotube transistors: The future?," Notre Dame, IN, Mar. 2009.
46. Arizona State University, "Toward manufacturable vertical carbon nanotube nanoelectronic devices," Tempe, AZ, Nov. 2008.
47. IBM T. J. Watson Research Center, "Templated vertical carbon nanotubes for nanoelectronics," Yorktown Heights, NY, Sept. 2008.

Selected Patents

1. **A. D. Franklin**, A. Afzali-Ardakani, G. S. Tulevski, "DNA sequencing using a suspended carbon nanotube," U.S. Patent 9428805, ISSUED August 30, 2016.
2. **A. D. Franklin**, D. B. Farmer, J. T. Smith, "Self-aligned double-gate graphene transistors," U.S. Patent App. No. 13/693700, filed December 2012.
3. **A. D. Franklin**, J. T. Smith, G. S. Tulevski, "Transistors from vertical stacking of carbon nanotube thin films," U.S. Patent App. No. 13/679613, filed November 2012.
4. **A. D. Franklin**, J. T. Smith, D. B. Farmer, S. Oida, "Vertical stacking of graphene in a field-effect transistor," U.S. Patent App. No. 13/683148, filed November 2012.
5. **A. D. Franklin**, G. S. Tulevski, J. T. Smith, "Device for electrical characterization of molecules using CNT-nanoparticle-molecule-nanoparticle-CNT structure," U.S. Patent App. No. 13/674492, filed November 2012.
6. J. T. Smith, **A. D. Franklin**, G. S. Tulevski, D. B. Farmer, "Carbon nanotube devices with unzipped low-resistance contacts," U.S. Patent App. No. 13/664008, filed October 2012.
7. **A. D. Franklin**, S. O. Koswatta, J. T. Smith, "Gate-all-around carbon nanotube transistor with selectively-doped spacers," U.S. Patent 8609481, ISSUED December 17, 2013.
8. **A. D. Franklin**, J. T. Smith, S. -J. Han, P. M. Solomon, "Contacts-first self-aligned carbon nanotube transistor with gate-all-around," U.S. Patent 8674412, ISSUED March 18, 2014.
9. J. T. Smith, **A. D. Franklin**, C. D. Dimitrakopoulos, "Sub-10nm graphene nanoribbon lattices," U.S. Patent 8685844, ISSUED April 1, 2014.

10. **A. D. Franklin**, J. T. Smith, Q. Cao, "Double contacts for carbon nanotube thin film devices," U.S. Patent 8741751, ISSUED June 3, 2014.
11. J. T. Smith, **A. D. Franklin**, C. D. Dimitrakopoulos, "Transport conduits for contacts to graphene," U.S. Patent 8637850, ISSUED January 28, 2014.
12. **A. D. Franklin**, S. -J. Han, A. A. Bol, "Semiconductor device including graphene layer and method of making the semiconductor device," U.S. Patent 9064842, ISSUED June 23, 2015.
13. S. -J. Han, **A. D. Franklin**, Z. Chen, "Graphene devices with local dual gates," U.S. Patent App. No. 20120175594 A1, filed January 7, 2011.
14. **A. D. Franklin**, S. -J. Han, Z. Chen, "Vertical stacking of carbon nanotube arrays for current enhancement and control," U.S. Patent 8288759, ISSUED October 16, 2012.
15. J. C. Claussen, **A. D. Franklin**, T. S. Fisher, D. M. Porterfield, "Electrochemical biosensor," U.S. Patent 8715981, ISSUED May 6, 2014.
16. **A. D. Franklin**, J. B. Hannon, G. Tulevski, Z. Chen, "Local bottom gates for graphene and carbon nanotube devices," U.S. Patent 8124463, ISSUED February 28, 2012.
17. **A. D. Franklin**, T. D. Sands, T. S. Fisher, D. B. Janes, "Field effect transistor fabrication from carbon nanotubes," U.S. Patent 8872154, ISSUED October 28, 2014.
18. **A. D. Franklin**, M. R. Maschmann, T. S. Fisher, T. D. Sands, "Contact metallization of carbon nanotubes," U.S. Patent No. 2009/0194424 A1, filed August 6, 2009.

Grants and Sponsored Research Projects

1. PI: A. Chilkoti, co-PI: **A. D. Franklin**, "A Point-of-Injury Screening Assay for Tactical Damage Control Resuscitation," *CDMRP: Defense Medical Research and Development, JPC-6 Combat Casualty Care Research Program*
\$1,500,000: May 2017 - Apr. 2020
2. co-PIs: **A. D. Franklin**, D. Mitzi, "Development of Low-Electron Affinity Buffer Layers for High Performance Earth-Abundant Solar Cells," *Duke Energy Research Seed Funding*
\$39,864: Jul. 2017 - Jun. 2018
3. PI: **A. D. Franklin**, "Understanding and Accessing the Ultra-sensitivity of Carbon Nanotubes," *Duke School of Medicine (SOM) Facility Voucher Program*
\$9,000: Jan. 2017 - Dec. 2017
4. PI: **A. D. Franklin**, "1.2.2 Nanoelectronics and nanosensors for Army applications: Exploring the vertical to plane electronic properties of layered two-dimensional materials," *Army Research Lab (ARL)*
\$35,000: Sept. 2016 - Aug. 2017
5. PI: **A. D. Franklin**, "EAGER: Exploring the Negative Capacitance Effect from Hf-based Ferroelectrics and 2D Nanomaterials for Low-Voltage Transistors," *National Science Foundation (NSF)*
\$150,000: Oct. 2016 - Sept. 2018
6. PI: **A. D. Franklin**, "Arrays of nanowire transistors: Fabrication and device performance," *Illumina, Inc*
\$450,000: Apr. 2016 - Apr. 2019
7. PI: **A. D. Franklin**, "Engineering Atomic Layer Deposited Contact Interfaces to Low-Dimensional Nanomaterials for Improved Scaled Transistor Performance," *National Science Foundation (NSF)*
\$358,086: June 2015 - May 2018
8. PI: **A. D. Franklin**; co-PI: M. Brooke, "Nanomaterial-Enabled Printed Electronics for Advanced Tire Monitoring System," *Fetch Automotive Design Group, LLC*
\$380,998: July 2015 - Apr. 2017
9. PI: **A. D. Franklin**; co-PIs: M. Therien, J. Liu, "Printing Electronic Circuits Using Nanomaterial Inks," *Duke Pratt Seed Fund*
\$37,600: Nov. 2014 - Nov. 2015

Academic and Professional Service

Executive Director of Graduate Studies

Duke, ECE Department (Sept. 2017 - present)

Journal & Proposal Reviewer

Journal Reviewer: *Science, Nature, Nature Nanotechnol., Nature Comm., Nano Lett., ACS Nano, ACS Appl. Mater. Interfaces, Sci. Adv., Sci. Rep., Appl. Phys. Lett., Adv. Mater., Adv. Func. Mater., Adv. Electronic Mater., Adv. Mater. Interfaces, PLOS One, IEEE Trans. Nanotechnol., IEEE Electron Device Lett., IEEE Trans. Electron Devices, Nanotechnology, Thin Solid Films, J. Phys. D: Appl. Phys., MRS Proceedings, New J. Phys., J. Phys. Chem., J. Electronic Mater., Surface Rev. Lett., Mater. Chem. Phys., Physica B: Condensed Matter, Nanoscale Res. Lett., MRS Comm., J. Computational Electronics, Appl. Phys. A, Semicond. Sci. Technol., Nano Res.*

Grant/Proposal Reviewer: *National Science Foundation* (since 2011)

Conferences

Technical Program Chair: *75th Device Research Conference - DRC* (2017)

Technical Program Vice-Chair: *74th Device Research Conference - DRC* (2016)

Subcommittee Chair: *International Electron Device Meeting (IEDM), Nano Device Technology* (2016 - present)

Technical Program Committee Member: *International Electron Device Meeting - IEDM* (2014 - present), *Device Research Conference - DRC* (2012 - present), *International Conference on Electron, Ion, and Photon Beam Technology and Nanofabrication - EIPBN* (2014 - 2016), *IEEE Photonics Society Summer Topical Meeting* (2015), *Gordon Research Conference - Nanostructure Fabrication* (2014)

Session/Symposium Organizer: *TechConnect Nanoelectronics Section* (June 2015), *Materials Research Society - MRS* (Fall 2014, Fall 2012), *Applied Physics Society Meeting - APS* (March 2013), *IEEE International Conference on Nanotechnology - IEEE Nano* (Aug. 2013)

Short Course Organizer: *Device Research Conference - DRC* (2013, "2D Materials Beyond Graphene")

Workshop Co-organizer: *Carbon Nanotubes for Digital Electronics Workshop @ NIST* (2012)

IBM Physical Science Department Seminar Chair 2011 - 2013

Academic Committees

(Duke-wide) Misconduct in Research Committee: *Appointed member* (Sept. 2017 - Aug. 2020)

(Duke-wide) Academic Council: *Elected member* (Aug. 2015 - Aug. 2017)

(Pratt-wide) Engineering Faculty Council: *Elected member* (Aug. 2015 - Aug. 2017)

ECE Department: *Graduate Studies Committee GSC* (Sept. 2017 - present), *Undergraduate Studies Committee UGSC* (Sept. 2016 - present), *TOP ECE Faculty Recruitment Committee* (Spring 2017 - present), *ECE Staff Assistant Hiring Committee* (Apr. 2015)

Chemistry Department: *Regular Rank Non Tenure Track Faculty Development* (2017-2018), *Research Propositional Examination Committee* (Fall 2015), *Research Faculty Committee* (2015 - 2016)

Miscellaneous: *Shared Materials Instrumentation Facility (SMIF) Advisory Committee* (Aug. 2015 - present), *Pratt Dean Search Engineering Faculty Council Committee* (Nov. - Dec. 2015), *Dean's Award for Excellence in Mentoring Selection Committee* (Dec. 2015)

Examination Committees

Final Defense: *Xinyu Liu* (July 2017), *David Miller* (Nov. 2016), *Liji Chen* (June 2016), *Erich Radauscher* (Apr. 2016)

Preliminary Exams: *Wiley Dunlap-Shohl* (June 2017), *Felicia McGuire* (May 2017), *Callie Woods* (Apr. 2017), *Mutya Cruz* (Apr. 2017), *Xinyu Liu* (Sept. 2016), *Ugonna Ohiri* (June 2016), *Daniel Joh* (May 2016), *Christopher Reyes* (Apr. 2016), *George Bullard* (Apr. 2016), *Qiwei Han* (Apr. 2015), *Lianjun Ellie Zheng* (Apr. 2015), *Matthew Catenacci* (Apr. 2015), *Erich Radauscher* (Mar. 2015)

Qualifying Exams: *Wade Wilson* (May 2017), *Fan Wang* (Apr. 2017), *Raul Vyas* (Dec. 2016), *Steven Noyce* (Dec. 2016), *Philip Herr* (Dec. 2016), *Xin Song* (Dec. 2016), *Tasso von Windheim* (Nov. 2016), *Zhongxi Li* (Nov. 2016), *Yuh-Chen Lin* (Nov. 2016), *Katherine Price* (June 2016), *Wiley Dunlap-Shohl* (June 2016), *Jimmy Thostenson* (Apr. 2016), *Zhihui Cheng* (Feb. 2016), *Laura Pulido* (Oct. 2015), *Callie Woods* (Sept. 2015), *Felicia McGuire* (Apr. 2015)

Prior to Duke

Corporate Liaison from IBM: *SRC-GRC Task at Georgia Tech* (2010 - 2014), *Nanoelectronics Research Initiative (NRI) funded centers* (2010 - 2013)

Purdue University ECE Graduate Committee Member 2008

Birck Nanotechnology Center Student Advisory Councilmember, Purdue University 2006 - 2008

Graduate Student Mentor to Undergraduate Research Fellows, Purdue University

2006 – 2007

Research and Professional Experience

Duke University, Durham, NC

Associate Professor, Department of Electrical and Computer Engineering & Department of Chemistry 2014 – Present

- Direct research program on nanoelectronics and printed electronic devices for diverse applications.

IBM, T. J. Watson Research Center, Yorktown Heights, NY

Research Staff Member

2008 – 2014

- Investigated low-dimensional materials for electronics applications.
- Developed integration processes for carbon nanotubes and graphene into nanoelectronic devices.
- Studied and improved scaling behavior in carbon nanotube and graphene devices.
- Explored application of carbon nanotubes to supercapacitor electrodes.
- Studied thin-film transistors from carbon nanotubes and graphene for flexible electronics applications.
- Implemented carbon nanotubes and/or graphene for electrodes in photovoltaic cells.

Purdue University, Birck Nanotechnology Center, School of Electrical and Computer Engineering, West Lafayette, IN

NSF Fellow, PhD Student

2005 – 2008

- Developed process for nanowire growth by penetrating alumina barrier in porous anodic alumina (PAA).
- Optimized electrodeposition process to achieve controlled formation of Pd nanocubes decorating CNTs for application in biosensors.
- Conducted extensive optimization studies on CNT synthesis using plasma-enhanced CVD.
- Designed and implemented technique for obtaining long-range ordered thin-film PAA.
- Developed process for embedding PAA in customizable patterns within SiO₂.
- Fabricated and characterized the first completely vertical two-terminal CNT devices.
- Established surround gates on vertical CNT channels.
- Developed process for straightforward control of CNT channel length for vertical nanoelectronics.

Intel Corporation, Chandler, AZ

2004 – 2005

Component Design Engineer

- Designed and validated various units for the Intel chipset projects.
- Implemented and enhanced skills in logic design, debugging, and project management.

Institute for Nanoelectronics and Computing, Purdue University, West Lafayette, IN

NASA Summer Undergraduate Research Intern

2004

- Studied effects of pre-growth catalyst annealing on CNT synthesis in plasma-enhanced CVD.
- Contributed to the design/characterization of modified PAA for synthesizing vertical CNT channels.

Honeywell, Phoenix, AZ

2003 – 2004

Electrical Engineer Intern (Automated Flight Controls Systems)

- Performed manual computer tests on various mixed signal designs.
- Sponsored by Corporate Leaders Program, which provided interaction with industry leaders and enhancement of communication and presentation skills through monthly activities.

Arizona State University, Department of Electrical Engineering, Tempe, AZ

Undergraduate Researcher

2003 – 2004

- Performed electrical characterization of solid-state ionic memory devices.

Teaching Experience

Duke University, Durham, NC

2014 – present

Associate Professor, Department of Electrical & Computer Engineering and Department of Chemistry

- *ECE 230L* – Fall 2017. Taught undergraduate core course on microelectronic devices & circuits.
- *ECE 230L* – Spring 2017. Taught undergraduate core course on microelectronic devices & circuits.
- *ECE/NANOSCI 511* – Spring 2017. Updated content for, developed, and taught graduate-level course on foundations of nanoscale science & technology.
- *ECE 230L* – Fall 2016. Taught undergraduate core course on microelectronic devices & circuits.
- *ECE 590.05* – Spring 2016. Updated and taught graduate-level course on nanoelectronic devices.
- *ECE 230L* – Fall 2015. Taught undergraduate core course on microelectronic devices & circuits.
- *CHEM 548* – Spring 2015. Developed and taught graduate-level course on solid-state materials/chemistry.
- *ECE 590.08* – Fall 2014. Developed and taught graduate-level course on nanoelectronic devices.

Columbia University, New York, NY

2013 – 2014

Adjunct Assistant Professor, Department of Electrical Engineering

- Developed and taught graduate-level courses on emerging and low-dimensional nanoelectronic devices.

Ivy Tech Community College, Lafayette, IN

2007 - 2008

Adjunct Faculty

- Taught undergraduate math courses, including all lecturing and grading.
- Received highest ratings in department from student reviews.

Community Service

IBM Mentor to High School Students

2011 - 2014

Pathways in Technology Early College High School (P-TECH)

- One-on-one mentoring of P-TECH students in STEM disciplines.

National Engineers Week Volunteer

2005, 2011 - present

Intel Corporation, IBM, Duke

- Judge local and national high school science fair projects.
- Visit high school science classes to motivate students to pursue careers in science and engineering.

High School Seminary Teacher

2001 - 2007

- Daily taught two high school seminary classes of 30+ students for four years.

Global Tech Leaders Symposium Delegate

2004

Corporate Leaders Program, Arizona State University

- Worked in diverse teams to provide technological service to communities in Singapore and Tokyo.

Boy Scouts of America Explorer Post Leader

2001 - 2003

- Led group of 15 boys through high-adventure activities and character-building merit badge classes.

Full-time Church Missionary

1998 - 2000